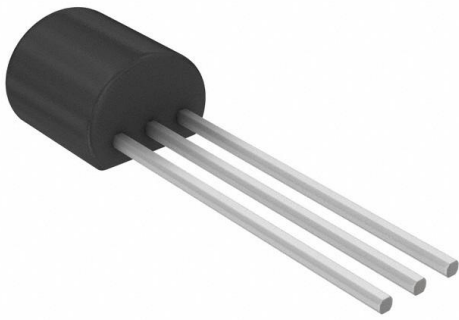


# ZTX958STOA Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	ZTX958STOA-DG
Manufacturer	<a href="#">Diodes Incorporated</a>
Manufacturer Product Number	ZTX958STOA
Description	TRANS PNP 400V 0.5A E-LINE
Detailed Description	Bipolar (BJT) Transistor PNP 400 V 500 mA 85MHz 1 .2 W Through Hole E-Line (TO-92 compatible)



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

ZTX958STOA

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

400 V

Current - Collector Cutoff (Max):

50nA (ICBO)

Power - Max:

1.2 W

Operating Temperature:

-55°C ~ 200°C (TJ)

Package / Case:

E-Line-3, Formed Leads

Base Product Number:

ZTX958

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

500 mA

Vce Saturation (Max) @ Ib, Ic:

400mV @ 100mA, 500mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 500mA, 10V

Frequency - Transition:

85MHz

Mounting Type:

Through Hole

Supplier Device Package:

E-Line (TO-92 compatible)

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

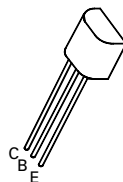
# PNP SILICON PLANAR MEDIUM POWER HIGH CURRENT TRANSISTOR

## ZTX958

ISSUE 3 – JUNE 94

### FEATURES

- \* 0.5 Amp continuous current
- \* Up to 1.5 Amps peak current
- \* Very low saturation voltage
- \* Excellent gain characteristics up to 1 Amp
- \* Spice model available



**E-Line**  
**TO92 Compatible**

### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	$V_{CBO}$	-400	V
Collector-Emitter Voltage	$V_{CEO}$	-400	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Peak Pulse Current	$I_{CM}$	-1.5	A
Continuous Collector Current	$I_C$	-0.5	A
Practical Power Dissipation*	$P_{totp}$	1.58	W
Power Dissipation at $T_{amb}=25^{\circ}C$	$P_{tot}$	1.2	W
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200	$^{\circ}C$

\*The power which can be dissipated assuming the device is mounted in a typical manner on a P.C.B. with copper equal to 1 inch square minimum

### ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-400	-600		V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CER}$	-400	-600		V	$I_C = -1\mu A, R_B \leq 1K\Omega$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-400	-550		V	$I_C = -10mA^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-6	-8		V	$I_E = -100\mu A$
Collector Cut-Off Current	$I_{CBO}$			-50 -1	nA $\mu A$	$V_{CB} = -300V$ $V_{CB} = -300V, T_{amb} = 100^{\circ}C$
Collector Cut-Off Current	$I_{CER}$ $R \leq 1K\Omega$			-50 -1	nA $\mu A$	$V_{CB} = -300V$ $V_{CB} = -300V, T_{amb} = 100^{\circ}C$
Emitter Cut-Off Current	$I_{EBO}$			-10	nA	$V_{EB} = -6V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-100 -150 -300	-150 -200 -400	mV mV mV	$I_C = -10mA, I_B = -1mA^*$ $I_C = -100mA, I_B = -10mA^*$ $I_C = -500mA, I_B = -100mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-790	-900	mV	$I_C = -500mA, I_B = -100mA^*$

# ZTX958

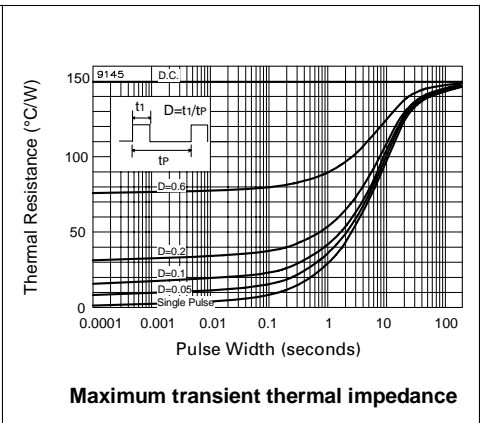
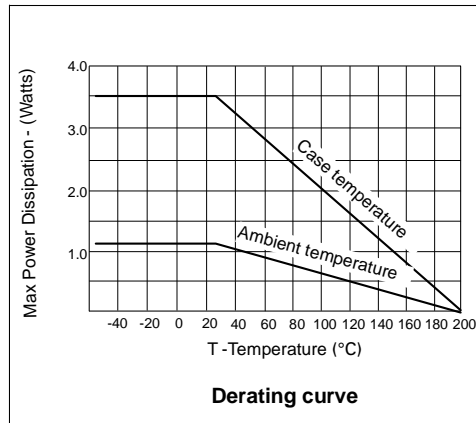
## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ )

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-690	-800	mV	$I_C = -500\text{mA}$ , $V_{CE} = -10\text{V}^*$
Static Forward Current Transfer Ratio	$h_{FE}$	100 100 10	200 200 20	300		$I_C = -10\text{mA}$ , $V_{CE} = -10\text{V}^*$ $I_C = -500\text{mA}$ , $V_{CE} = -10\text{V}^*$ $I_C = -1\text{A}$ , $V_{CE} = -10\text{V}^*$
Transition Frequency	$f_T$		85		MHz	$I_C = -100\text{mA}$ , $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Output Capacitance	$C_{obo}$		19		pF	$V_{CB} = -20\text{V}$ , $f = 1\text{MHz}$
Switching Times	$t_{on}$ $t_{off}$		104 2400		ns ns	$I_C = -500\text{mA}$ , $I_{B1} = -50\text{mA}$ $I_{B2} = 50\text{mA}$ , $V_{CC} = -100\text{V}$

\*Measured under pulsed conditions. Pulse width=300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$

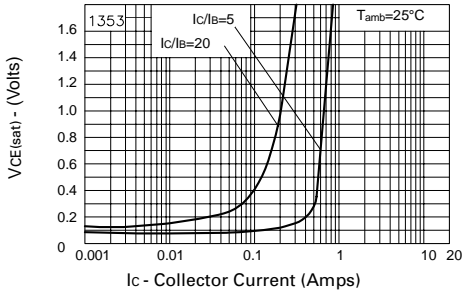
## THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	MAX.	UNIT
Thermal Resistance: Junction to Ambient Junction to Case	$R_{th(j-amb)}$ $R_{th(j-case)}$	150 50	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$

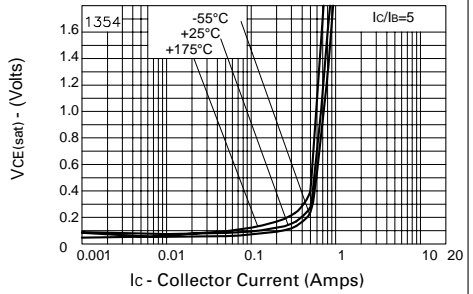


# ZTX958

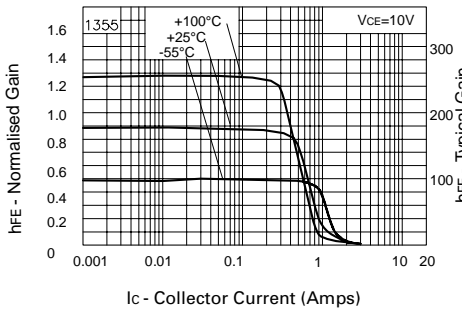
## TYPICAL CHARACTERISTICS



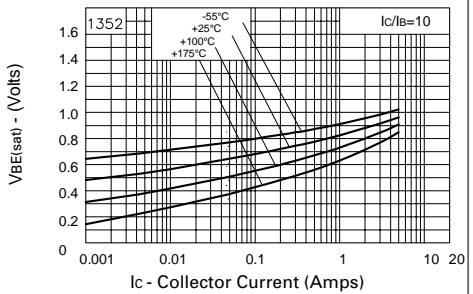
**$V_{CE(sat)}$  v  $I_C$**



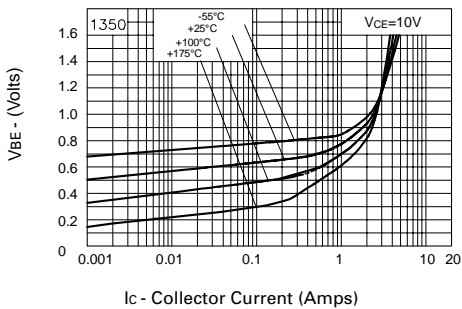
**$V_{CE(sat)}$  v  $I_C$**



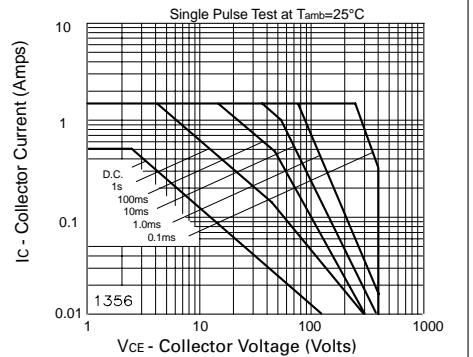
**$h_{FE}$  v  $I_C$**



**$V_{BE(sat)}$  v  $I_C$**



**$V_{BE(on)}$  v  $I_C$**



**Safe Operating Area**

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